

## KSC3074

## **High Power Switching**

Complement to KSA1244



## **NPN Epitaxial Silicon Transistor**

## Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	50	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current	5	Α
I <sub>B</sub>	Base Current	1	Α
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> =25°C)	1	W
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	20	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

## **Electrical Characteristics** $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = 10 \text{mA}, I_B = 0$	50			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 50V, I_{E} = 0$			1	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			1	μΑ
h <sub>FE1</sub>	DC Current Gain	$V_{CE} = 1V$ , $I_C = 1A$	70		240	
h <sub>FE2</sub>		$V_{CE} = 1V, I_{C} = 3A$	30			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = 3A, I_B = 0.15A$			0.5	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	$I_C = 3A, I_B = 0.15A$		0.9	1.2	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 4V$ , $I_{C} = 1A$		120		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10V, f = 1MHz		80		pF
t <sub>ON</sub>	Turn ON Time	$V_{CC} = 30V, I_{C} = 3A$		0.1		μs
t <sub>STG</sub>	Storage Time	I <sub>B1</sub> = - I <sub>B2</sub> =0.15A		1		μs
t <sub>F</sub>	Fall Time	$R_L = 10\Omega$		0.1		μs

## **h**<sub>FE</sub> Classification

Classification	0	Y	
h <sub>FE1</sub>	70 ~ 140	120 ~ 240	

# **Typical Characteristics**

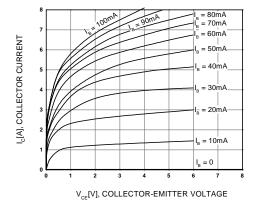


Figure 1. Static Characteristic

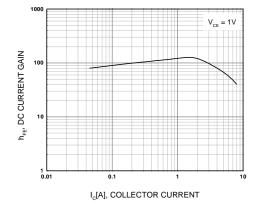


Figure 2. DC current Gain

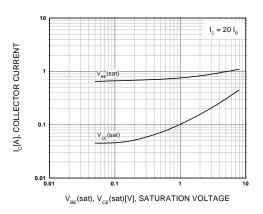


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

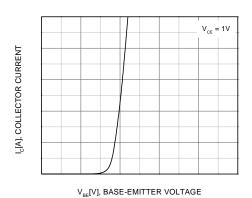


Figure 4. Base-Emitter on Voltage

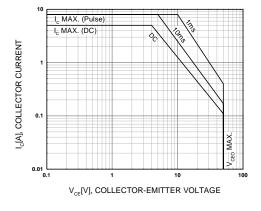


Figure 5. Safe Operating Area

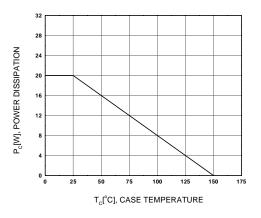
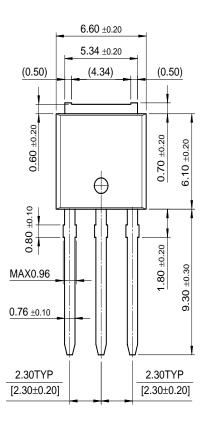


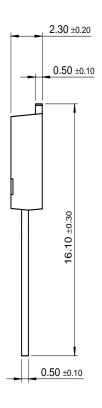
Figure 6. Power Derating

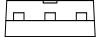
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# **Package Demensions**

# I-PAK







Dimensions in Millimeters

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